TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

# **TA8127NG, TA8127FG**

3V AM / FM 1chip Tuner IC

TA8127NG and TA8127FG are the AM / FM 1chip tuner ICs, which are designed for portable radios and 3V headphone radios.

#### **Features**

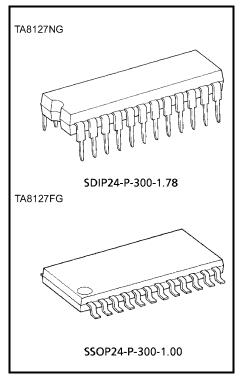
• Built-in

FM F / E, AM / FM IF and FM MPX

- AM detector coil and IF coupling condenser are not needed.
- Compact package

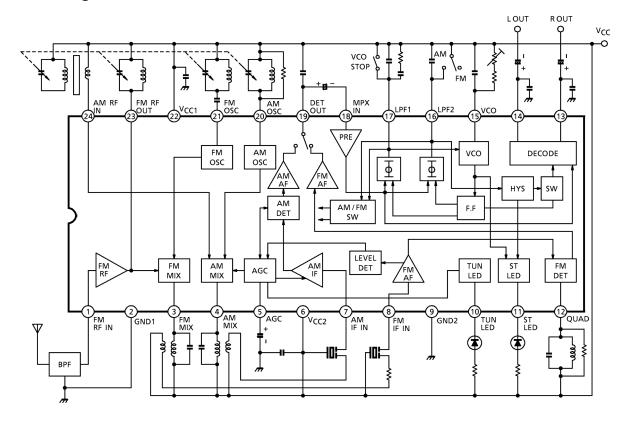
TA8127NG: Shrink DIP 24 pin (1.78mm pitch) TA8127FG: Mini flat packge 24 pin

• Operating supply voltage range  $V_{CC} = 1.8 \sim 7.0 V (Ta = 25 \circ C)$ 



Weight SDIP24-P-300-1.78: 1.2g (typ.) SSOP24-P-300-1.00: 0.31 (typ.)

## **Block Diagram**



# **Explanation Of Terminals**

Pin No.	ltem	Internal Circuit	DC Voltage (V) (at no Signal)		
	-		AM	FM	
1	FM-RF IN	FM-RF OUT (23)  1	0	0.7	
2	GND1 (GND for RF stage)	_	0	0	
3	FM MIX	Vcc1 22 3	3.0	3.0	
4	AM MIX	V <sub>CC1</sub> (2)  MIX  GND1 (2)	3.0	3.0	
5	AGC (AM AGC)	S IF AGC  RF AGC  GND2 9		0	
6	V <sub>CC2</sub> (V <sub>CC</sub> for IF / MPX stage)	_	3.0	3.0	
7	AM IF IN	VCC2 6 C F F F F F F F F F F F F F F F F F F	3.0	3.0	
8	FM IF IN	V <sub>CC2</sub> 6 G G G G G G G G G G G G G G G G G G	3.0	3.0	

Pin No.	Item	Internal Circuit	DC Voltage (V) (at no Signal)		
			AM	FM	
9	GND2 (GND for IF / MPX stage)	_	0	0	
10	TUN LED (tuning LED)	V <sub>CC2</sub> 6 10 10 GND2 9	_	_	
11	ST LED (stereo LED)	76kHz ————————————————————————————————————	ı	_	
12	QUAD (FM QUAD. Detector)	V <sub>CC2</sub> 6	3.0	3.0	
13 14	R-OUT (R-ch output) L-OUT (L-ch output)	V <sub>CC2</sub> 6 3 4 5 6 6 6 6 6 6 6 6 6 6 6 6 6 6 6 6 6 6	1.0	1.0	
15	vco	VCC2 6 AMP 15 GND2 9	2.5	2.5 (VCO stop mode)	
16	LPF2 • LPF terminal for synchronous detector • Bias terminal for AM / FM SW circuit $V_{16} = V_{CC} \rightarrow AM (VCO \text{ stop})$ $V_{16} = OPEN \rightarrow FM$	GND2 9	3.0	2.2 (VCO stop mode 2.7)	
17	LPF1  • LPF terminal for phase detector  • VCO stop terminal  V <sub>7</sub> = V <sub>CC</sub> →VCO stop	GND2 9	2.7	2.2	

Pin No.	Item	Internal Circuit	DC Vol	tage (V) Signal)
1 11110.	i.c.iii	monal should	AM	FM
18	MPX IN	(B) (GND2 (9)	0.7	0.7
19	DET OUT	WCC2 6  AM  FM  B  B  COM  B  COM  COM  COM  COM  COM	1.5	1.2
20	AM OSC	V <sub>CC1</sub> 22 MIX  GND1 2	3.0	3.0
21	FM OSC	V <sub>CC1</sub> (2) (2) MIX (4) GND1 (2)	3.0	3.0
22	V <sub>CC1</sub> (V <sub>CC</sub> for RF stage)	_	3.0	3.0
23	FM RF OUT	Cf. Pin(1)	3.0	3.0
24	AM RF IN	Vcc1 22 24 GND1 2	3.0	3.0

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2006-04-11

## Absolute Maximum Ratings (Ta = 25°C)

Characteris	stic	Symbol	Rating	Unit	
Supply voltage		V <sub>CC</sub>	8	٧	
LED current		I <sub>LED</sub>	10	mA	
LED voltage		V <sub>LED</sub>	8	V	
Power dissipation	TA8127NG	P <sub>D</sub>	1200	mW	
rower dissipation	TA8127FG	(Note)	400	11100	
Operating temperature		T <sub>opr</sub>	-25~75	°C	
Storage temperature		T <sub>stg</sub>	-55~150	°C	

Note: Derated above 25°C in the proportion of 9.6mW / °C for TA8127NG and of 3.2mW / °C for TA8127FG.

### **Electrical Characteristics**

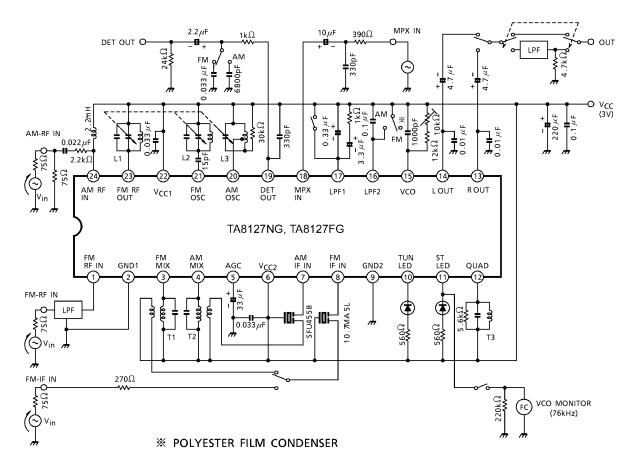
Unless Otherwise Specified,

Ta = 25°C,  $V_{CC}$  = 3V, F / E: f = 83MHz,  $f_m$  = 1kHz FM IF: f = 10.7MHz,  $\Delta f$  = ±22.5kHz,  $f_m$  = 1kHz AM: f = 1MHz, MOD = 30%,  $f_m$  = 1kHz MPX:  $f_m$  = 1kHz

Characteristic		Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit	
Sunn	ly current		1	V <sub>in</sub> = 0, FM mode	_	13.2	20.0	mA	
Supp	y current	I <sub>CC (AM)</sub>	1	V <sub>in</sub> = 0, AM mode	_	8.4	13.5	IIIA	
F/E	Input limiting voltage	Vin (lim.)	1	– 3dB limiting	_	10.0	_	dBµV EMF	
F / E	Local OSC voltage	Vosc	2	f <sub>OSC</sub> = 72.3MHz	_	105	_	mV <sub>rms</sub>	
	Input limiting voltage	V <sub>in (lim.)</sub> IF	1	– 3dB limiting	40	46	53	dBµV EMF	
	Rcovered output voltage V <sub>OD</sub>		1	V <sub>in</sub> = 80dBμV EMF	55	80	110	mV <sub>rms</sub>	
FM IF	Signal to noise ratio	S/N	1	V <sub>in</sub> = 80dBµV EMF	_	70	_	dB	
lir-	Total harmonic distortion	THD	1	V <sub>in</sub> = 80dBμV EMF	_	0.4	_	%	
	AM rejection ratio	AM rejection ratio AMR		V <sub>in</sub> = 80dBμV EMF	_	32	_	dB	
	Lamp on sensitivity	VL	1	I <sub>L</sub> = 1mA	45	51	56	dBµV EMF	
	Gain	G <sub>V</sub>		V <sub>in</sub> = 26dBµV EMF	40	70	110	m\/	
	Recovered output voltage	V <sub>OD</sub>	1	V <sub>in</sub> = 60dBμV EMF	55	80	110	mV <sub>rms</sub>	
AM	Signal to noise ratio	S/N	1	V <sub>in</sub> = 60dBµV EMF	_	42	_	dB	
	Total harmonic distortion	THD	1	V <sub>in</sub> = 60dBμV EMF	_	1.0	_	%	
	Lamp on sensitivity	V <sub>L</sub>	1	I <sub>L</sub> = 1mA	20	25	30	dBµV EMF	
Pin(19) output resistance		D.,	1	FM mode	_	0.75	_	10	
- III( I	a) output resistance	R <sub>19</sub>	'	AM mode	_	12.5	_	kΩ	

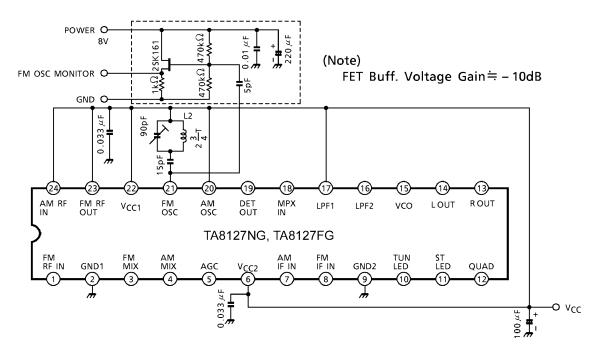
	Characteristic		Symbol	Test Cir– cuit	Test C	Test Condition		Тур.	Max.	Unit	
	Input resistan	ce	R <sub>IN</sub>	_	-	_	_	24	_	kΩ	
	Output resista	ince	R <sub>OUT</sub>	_	-	_	_	5	_	K12	
	Max. Compos signal input vo		V <sub>in (max.)</sub> stereo	1		L+R = 90%, P = 10% f <sub>m</sub> = 1kHz, THD = 3%		350	_	mV <sub>rms</sub>	
					L+R =	f <sub>m</sub> = 100Hz	_	42	_		
	Separation		Sep	1	135mV <sub>rms</sub>	f <sub>m</sub> = 1kHz	35	42	_	dB	
					$P = 15 \text{mV}_{\text{rms}}$ $f_{\text{m}} = 10 \text{kHz}$	_	42	_			
	Total harmonic distortion	Monaural	THD (monaural)	1	V <sub>in</sub> = 150mV <sub>rms</sub>		_	0.2	_	%	
MPX		Stereo	THD (stereo)	'	L+R = $135\text{mV}_{\text{rms}}$ , P = $15\text{mV}_{\text{rms}}$		_	0.2	_		
	Voltage gain		G <sub>V (MPX)</sub>	1	V <sub>in</sub> = 150mV <sub>rms</sub>		-5	-3	-1	dB	
	Channel balar	nce	C. B.	1	V <sub>in</sub> = 150mV <sub>rms</sub>		-2	0	2	uв	
	Stereo lamp	On	V <sub>L (ON)</sub>	1	Pilot input		_	8	16	m\/	
	sensitivity	Off	V <sub>L (OFF)</sub>	1	Pilot input	Pilot input		6	_	mV <sub>rms</sub>	
	Stereo lamp hysteresis		V <sub>H</sub>	1	To LED turn of LED turn on	To LED turn off from		2	_	mV <sub>rms</sub>	
	Caputure range		C. R.	1	P = 15mV <sub>rms</sub>		_	±3	_	%	
	Signal to noise ratio		S/N	1	V <sub>in</sub> = 150mV <sub>rm</sub>	_	70	_	dB		

#### **Test Circuit 1**



Using other types of condensers, there are some cases that the MPX does not do normal stereo action at high temperature or low temperature.

#### **Test Circuit 2**



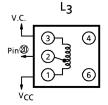
#### **Coil Data**

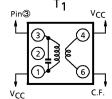
Coil No.	Test	L	Co	0.5			Turns			Wire	Reference
Coll No.	Freq. (Hz)	(µH)	(pF)	QO	1–2	2–3	1–3	1–4	4–6	(mmφ)	Reference
L <sub>1</sub> FM RF	100M	_		100	l	_	_	$2\frac{1}{2}$	_	0.5UEW	(S) 53T-037-202
L <sub>2</sub> FM OSC	100M	_		100		_	$2\frac{3}{4}$	_	_	0.5UEW	(S) 0258–244
L <sub>3</sub> AM OSC	796k	288	_	115	13	73	_	_	_	0.08UEW	(S) 4147-1356-038
T <sub>1</sub> FM MIX	10.7M	_	75	100	_	_	13	_	2	0.1UEW	(S) 2153-414-041
T <sub>2</sub> AM MIX	455k	_	180	120		_	180		15	0.08UEW	(S) 2150-2162-165
T <sub>3</sub> FM DET	10.7M	_	47	165	_	_	16	_	_	0.09UEW	(S) 2153-4095-122

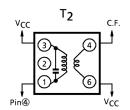
(S): SUMIDA electric CO., LTD











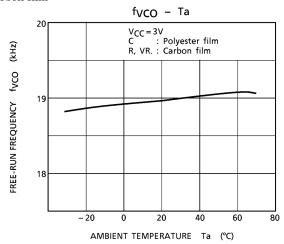


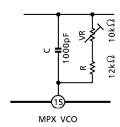
#### Hint On Use Of TA8127NG And TA8127FG

External parts of MPX VCO

(1) Temperature characteristic of MPX VCO free –run frequency. The temperature characteristic of MPX VCO is shown in the diagram as below. Select one with a better temperature characteristic (C, R and VR.) in use. We recommend,

C : Polyester film R, VR: Carbon film





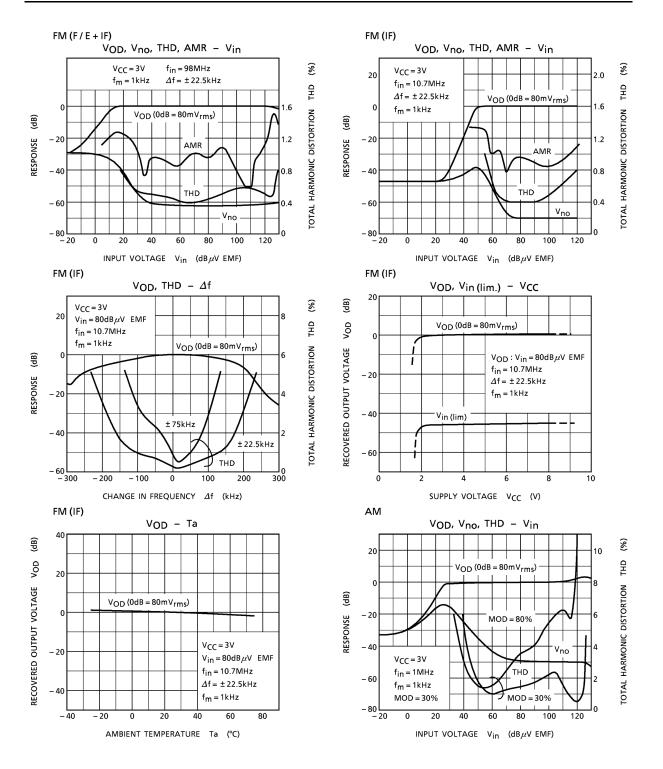
(2) Value of the external parts

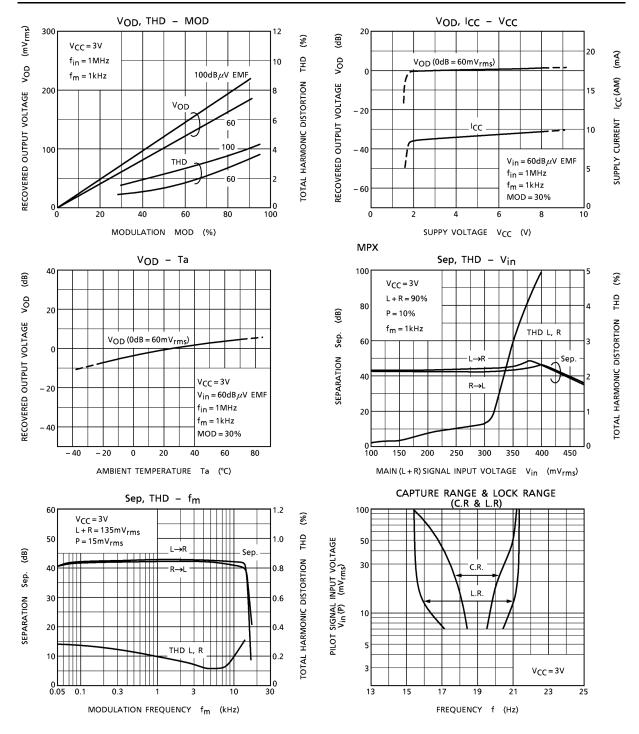
We recommend to set up these value as below.

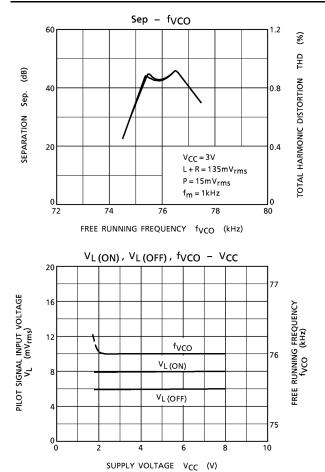
 $R = 12k\Omega$ 

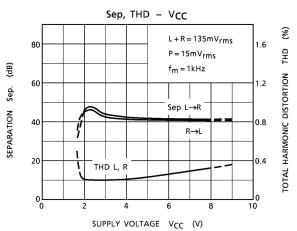
 $\mathrm{VR}=10\mathrm{k}\Omega$ 

C = 1000pF





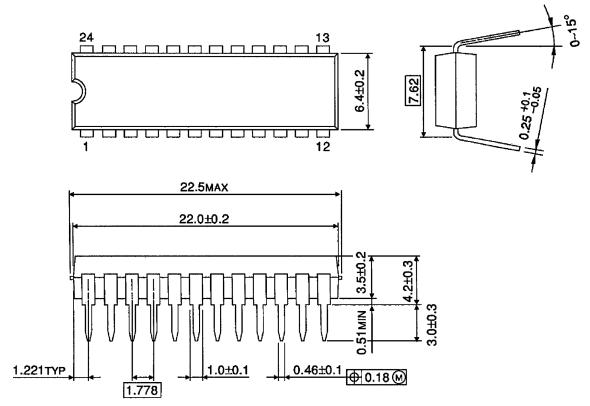




## **Package Dimensions**

SDIP24-P-300-1.78

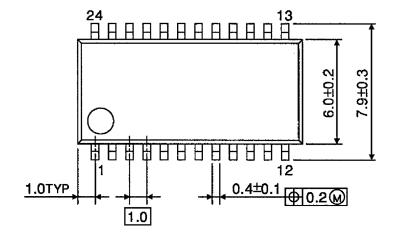


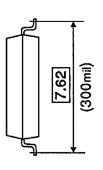


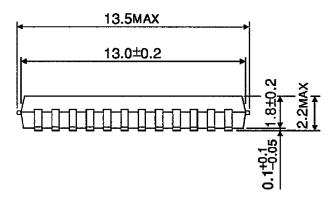
Weight: 1.2g (typ.)

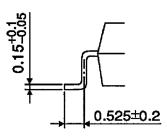
## **Package Dimensions**

SSOP24-P-300-1.00 Unit: mm









Weight: 0.31g (typ.)

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About solderability, following conditions were confirmed

- Solderability
  - (1) Use of Sn-37Pb solder Bath
    - · solder bath temperature = 230°C
    - · dipping time = 5 seconds
    - · the number of times = once
    - · use of R-type flux
  - (2) Use of Sn-3.0Ag-0.5Cu solder Bath
    - · solder bath temperature = 245°C
    - · dipping time = 5 seconds
    - · the number of times = once
    - · use of R-type flux